

MC78LXXA/LM78LXXA/MC78L05AA

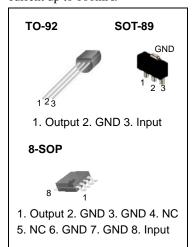
3-Terminal 0.1A Positive Voltage Regulator

Features

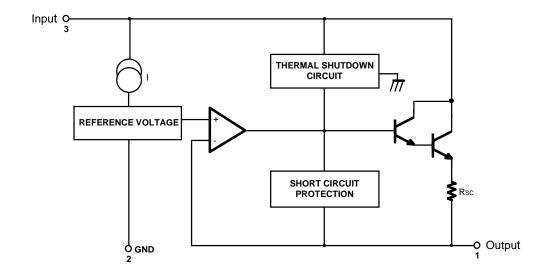
- Maximum Output Current of 100mA
- Output Voltage of 5V, 6V, 8V, 12V, 15V, 18V and 24V
- Thermal Overload Protection
- Short Circuit Current Limiting
- Output Voltage Offered in ±5% Tolerance

Description

The MC78LXXA/LM78LXXA/MC78L05AA series of fixed voltage monolithic integrated circuit voltage regulators are suitable for application that required supply current up to 100mA.



Internal Block Diagram



Absolute Maximum Ratings

Parameter	Symbol	Value	Unit
Input Voltage (for $V_O = 5V$ to $8V$) (for $V_O = 12V$ to $18V$) (for $V_O = 24V$)	Vı	30 35 40	V V V
Operating Junction Temperature Range	TJ	0 ~ +150	°C
Storage Temperature Range	TSTG	-65 ~ +150	°C
Thermal Resistance Junction-Case TO-92	R _θ JC	50	°C/W
Thermal Resistance Junction-Air TO-92 SOT-89 8-SOP	R _θ JA	150 225 160	°C/W °C/W °C/W

Electrical Characteristics(MC78L05A/LM78L05A)

(VI = 10V, IO = 40mA, 0° C \leq TJ \leq 125 $^{\circ}$ C, CI = 0.33μ F, CO = 0.1μ F, unless otherwise specified. (Note 1)

Parameter		Symbol	Cor	nditions	Min.	Тур.	Max.	Unit
Output Voltage		Vo	T _J = 25°C		4.8	5.0	5.2	V
Line Regulation (Not	:e1)	4)/0	T.J = 25°C	$7V \le V_I \le 20V$	-	8	150	mV
		ΔVΟ	1J = 25°C	$8V \leq V_I \leq 20V$	-	6	100	mV
Load Regulation (No	sto 1)	4)/0	T. 25°C	$1mA \le IO \le 100mA$	-	11	60	mV
Load Regulation (No	nte i)	ΔVΟ	TJ = 25°C	$1mA \leq I_O \leq 40mA$	-	5.0	30	mV
			7V ≤ VI ≤ 20V	$1mA \le IO \le 40mA$	-	-	5.25	V
Output Voltage	Output Voltage		$7V \le V_I \le V_{MAX}$ (Note2)	$1mA \leq I_O \leq 70mA$	4.75	-	5.25	V
Quiescent Current		lQ	T _J = 25°C		-	2.0	5.5	mA
Quiescent Current	With Line	ΔlQ	8V ≤VI ≤ 20V		-	-	1.5	mA
Change	With Load	ΔlQ	1mA ≤ I _O ≤ 40 m	nA	-	-	0.1	mA
Output Noise Voltage	Output Noise Voltage VN		TA = 25°C, 10Hz	z ≤ f ≤ 100kHz	-	40	-	μV/Vo
Temperature Coefficient of V_O $\Delta V_O/\Delta T$		IO = 5mA		-	-0.65	-	mV/°C	
Ripple Rejection RR $f = 120$ Hz, $8V \le$		V _I ≤ 18V, T _J = 25°C	41	80	-	dB		
Dropout Voltage		VD	T _J = 25°C		-	1.7	-	V

^{1.} The maximum steady state usable output current and input voltage are very dependent on the heat sinking and/or lead length of the package. The data above represent pulse test conditions with junction temperature as indicated at the initiation of tests.

^{2.} Power dissipation $PD \le 0.75W$.

Electrical Characteristics(MC78L06A) (Continued)

(VI = 12V, IO = 40mA, 0° C \leq TJ \leq 125 $^{\circ}$ C, CI = 0.33μ F, CO = 0.1μ F, unless otherwise specified. (Note 1)

Parameter		Symbol	Co	nditions	Min.	Тур.	Max.	Unit
Output Voltage		Vo	T _J = 25°C	T _J = 25°C		6.0	6.25	V
Line Regulation (No	to1)	ΔVο	T.J = 25°C	$8.5V \le V_I \le 20V$	-	64	175	mV
Line Regulation (No	ter)	ΔνΟ	1J = 25°C	$9V \le V_I \le 20V$	-	54	125	mV
Load Population (N	oto 1)	ΔVΩ	T 25°C	$1mA \le IO \le 100mA$	-	12.8	80	mV
Load Regulation (No	Jie i)	ΔνΟ	T _J = 25°C	$1mA \leq I_O \leq 70mA$	-	5.8	40	mV
Output Voltage		Vo	$8.5 \le V_I \le 20V, 1mA \le IO \le 40mA$		5.7	-	6.3	V
Output voltage		٧٥	$8.5 \le V_I \le V_{MAX}(Note), 1mA \le I_O \le 70mA$		5.7	-	6.3	V
Quiescent Current		lo.	TJ = 25°C		-	-	5.5	mA
Quiescent Current		IQ	T _J = 125°C		-	3.9	6.0	mA
Quiescent Current	With Line	ΔlQ	$9 \le V_I \le 20V$		-	-	1.5	mA
Change	With Load	ΔlQ	$1mA \le IO \le 40mA$	1	-	-	0.1	mA
Output Noise Voltage		٧N	T _A = 25°C, 10Hz	$\leq f \leq 100kHz$	-	40	-	μV/Vo
Temperature Coefficient of VO Δ VO/ Δ T $IO = 5mA$			-	0.75	-	mV/°C		
Ripple Rejection RF		RR	$f = 120Hz, 10V \le V_I \le 20V, T_J = 25^{\circ}C$		40	46	-	dB
Dropout Voltage		VD	TJ = 25°C		ı	1.7	-	V

^{1.} The maximum steady state usable output current and input voltage are very dependent on the heat sinking and/or lead length of the package. The data above represent pulse test conditions with junction temperature as indicated at the initiation of tests.

^{2.} Power dissipation $PD \le 0.75W$.

Electrical Characteristics(MC78L08A) (Continued)

(VI = 14V, IO = 40mA, 0° C \leq TJ \leq 125 $^{\circ}$ C, CI = 0.33μ F, CO = 0.1μ F, unless otherwise specified. (Note 1)

Parameter		Symbol	Cor	nditions	Min.	Тур.	Max.	Unit
Output Voltage		Vo	TJ = 25°C		7.7	8.0	8.3	V
Line Regulation (Note	51)	ΔVΩ	T _J = 25°C	$10.5 V \leq V_I \leq 23 V$	-	10	175	mV
Line Regulation (Note	=1)	ΔνΟ	1J = 25 C	$11V \leq V_I \leq 23V$	-	8	125	mV
Load Population (Not	·o1)	ΔVο	T _J = 25°C	$1mA \le I_O \le 100mA$	-	15	80	mV
Load Regulation (Not	. e 1)	ΔνΟ		$1mA \le IO \le 40mA$	-	8.0	40	mV
			$10.5V \leq V_I \leq 23V$	$1mA \leq I_O \leq 40mA$	7.6	-	8.4	V
Output Voltage	Output Voltage		10.5V ≤ V _I ≤ V _{MAX} (Note2)	$1mA \le IO \le 70mA$	7.6	-	8.4	V
Quiescent Current		IQ	T _J = 25°C		-	2.0	5.5	mA
Quiescent Current	With Line	ΔlQ	$11V \leq V_I \leq 23V$		-	-	1.5	mA
Change	With Load	ΔlQ	1mA ≤ I _O ≤ 40m	A	-	-	0.1	mA
Output Noise Voltage		VN	T _A = 25°C, 10Hz	z ≤ f ≤100kHz	-	60	-	μV/Vo
Temperature Coefficient of VO		ΔV0/ΔΤ	IO = 5mA		-	-0.8	-	mV/°C
Ripple Rejection		RR	$f = 120Hz, 11V \le VI \le 21V, TJ = 25^{\circ}C$		39	70	-	dB
Dropout Voltage		VD	T _J = 25°C		-	1.7	-	V

^{1.} The maximum steady state usable output current and input voltage are very dependent on the heat sinking and/or lead length of the package. The data above represent pulse test conditions with junction temperature as indicated at the initiation of tests.

^{2.} Power dissipation $P_D \le 0.75W$.

Electrical Characteristics(MC78L12A/LM78L12A) (Continued)

(VI = 19V, IO = 40mA, 0° C \leq TJ \leq 125 $^{\circ}$ C, CI = 0.33 μ F, CO = 0.1 μ F, unless otherwise specified. (Note1))

Parameter		Symbol	Cor	nditions	Min.	Тур.	Max.	Unit
Output Voltage		Vo	T _J = 25°C		11.5	12	12.5	V
Line Regulation (Note	01)	ΔVΩ	TJ = 25°C	$14.5 V \leq V_I \leq 27 V$	-	20	250	mV
Line Regulation (Not	E1)	ΔνΟ		$16V \leq V_I \leq 27V$	-	15	200	mV
Load Population (No.	to1)	۸\/۵	T,j = 25°C	$1mA \le IO \le 100mA$	-	20	100	mV
Load Regulation (No	le i)	ΔVΟ	1J = 25 C	$1mA \le IO \le 40mA$	-	10	50	mV
			$14.5V \le V_I \le 27V$	$1mA \le IO \le 40mA$	11.4	-	12.6	V
Output Voltage		Vo	14.5V ≤ V _I ≤ VMAX (Note2)	$1mA \le I_O \le 70mA$	11.4	-	12.6	V
Quiescent Current		lQ	T _J = 25°C		-	2.1	6.0	mA
Quiescent Current	With Line	ΔlQ	16V ≤ V _I ≤ 27V		-	-	1.5	mA
Change	With Load	ΔlQ	$1mA \le I_O \le 40m$	A	-	-	0.1	mA
Output Noise Voltage	Output Noise Voltage		T _A = 25°C, 10Hz	z ≤ f ≤ 100kHz	-	80	-	μV/Vo
Temperature Coefficient of VO		ΔV0/ΔΤ	IO = 5mA		-	-1.0	-	mV/°C
Ripple Rejection		RR	$f = 120Hz, 15V \le V_I \le 25V, T_J = 25^{\circ}C$		37	65	-	dB
Dropout Voltage		VD	T _J = 25°C		-	1.7	-	V

^{1.} The maximum steady state usable output current and input voltage are very dependent on the heat sinking and/or lead length of the package. The data above represent pulse test conditions with junction temperature as indicated at the initiation of tests.

^{2.} Power dissipation $P_D \le 0.75W$.

Electrical Characteristics(MC78L15A) (Continued)

(VI = 23V, IO = 40mA, 0° C \leq TJ \leq 125 $^{\circ}$ C, CI = 0.33 μ F, CO = 0.1 μ F, unless otherwise specified. (Note1))

Parameter		Symbol	Coi	nditions	Min.	Тур.	Max.	Unit
Output Voltage		Vo	T _J = 25°C	T _J = 25°C		15	15.6	V
Line Regulation (Note	21)	4)/0	TJ = 25°C	17.5V ≤ V _I ≤ 30V	-	25	300	mV
Line Regulation (Note	∃ 1)	ΔVΟ		$20V \leq V_I \leq 30V$	-	20	250	mV
Load Population (Not	to1)	41/0	T 25°C	$1mA \le IO \le 100mA$	-	25	150	mV
Load Regulation (Not	le i <i>)</i>	ΔVΟ	T _J = 25°C	$1mA \le IO \le 40mA$	-	12	75	mV
			17.5V ≤ V _I ≤ 30V	$1mA \le IO \le 40mA$	14.25	-	15.75	V
Output Voltage	Output Voltage		17.5V ≤ V _I ≤ VMAX (Note2)	$1mA \le I_O \le 70mA$	14.25	-	15.75	V
Quiescent Current		IQ	T _J = 25°C		-	2.1	6.0	mA
Quiescent Current	With Line	ΔlQ	$20V \le V_I \le 30V$		-	-	1.5	mA
Change	With Load	ΔlQ	1mA ≤ I _O ≤ 40m	A	-	-	0.1	mA
Output Noise Voltage)	VN	T _A = 25°C, 10Hz	z ≤ f ≤ 100kHz	-	90	-	μV/Vo
Temperature Coefficient of VO		ΔV0/ΔΤ	I _O = 5mA		-	-1.3	-	mV/°C
Ripple Rejection RR		RR	f = 120Hz, 18.5V≤V _I ≤28.5V, T _J = 25°C		34	60	-	dB
Dropout Voltage		VD	T _J = 25°C		-	1.7	-	V

^{1.} The maximum steady state usable output current and input voltage are very dependent on the heat sinking and/or lead length of the package. The data above represent pulse test conditions with junction temperature as indicated at the initiation of tests.

^{2.} Power dissipation $PD \le 0.75W$.

Electrical Characteristics(MC78L18A) (Continued)

(VI = 27V, IO = 40mA, 0° C \leq TJ \leq 125 $^{\circ}$ C, CI = 0.33μ F, CO = 0.1μ F, unless otherwise specified. (Note1))

Parameter		Symbol	Coi	nditions	Min.	Тур.	Max.	Unit
Output Voltage		Vo	T _J = 25°C	T _J = 25°C		18	18.7	V
Line Regulation (Note	21)	ΔVΩ	T.J = 25°C	$21 \text{V} \leq \text{V}_{\text{I}} \leq 33 \text{V}$	-	145	300	mV
Line Regulation (Note	∃ 1)	ΔνΟ	1J = 25°C	$22V \leq V_I \leq 33V$	-	135	250	mV
Load Bogulation (Not	to 1)	1)/0	T. 25°C	1mA ≤ Io≤100mA	-	30	170	mV
Load Regulation (Not	le i)	ΔVΟ	T _J = 25°C	$1mA \le I_O \le 40mA$	-	15	85	mV
			$21 \text{V} \leq \text{V}_{\text{I}} \leq 33 \text{V}$	$1mA \le IO \le 40mA$	17.1	-	18.9	V
Output Voltage		Vo	21V ≤ V _I ≤ VMAX (Note2)	$1mA \le I_O \le 70mA$	17.1	-	18.9	V
Quiescent Current		IQ	T _J = 25°C		-	2.2	6.0	mA
Quiescent Current	With Line	ΔlQ	$21 \text{V} \leq \text{V}_{\text{I}} \leq 33 \text{V}$		-	-	1.5	mA
Change	With Load	ΔlQ	$1mA \le IO \le 40m$	A	-	-	0.1	mA
Output Noise Voltage)	VN	T _A = 25°C, 10H;	z ≤ f ≤ 100kHz	-	150	-	μV/Vo
Temperature Coefficient of VO		ΔV0/ΔΤ	IO = 5mA		-	-1.8	-	mV/°C
Ripple Rejection RR		$f = 120Hz, 23V \le V_I \le 33V, T_J = 25^{\circ}C$		34	48	-	dB	
Dropout Voltage		VD	T _J = 25°C		-	1.7	-	V

^{1.} The maximum steady state usable output current and input voltage are very dependent on the heat sinking and/or lead length of the package. The data above represent pulse test conditions with junction temperature as indicated at the initiation of tests.

^{2.} Power dissipation $PD \le 0.75W$.

Electrical Characteristics(MC78L24A) (Continued)

 $(V_I=33V,\ I_O=40mA,\ 0^{\circ}C\leq T_J\leq 125^{\circ}C,\ C_I=0.33\mu F,\ C_O=0.1\mu F,\ unless\ otherwise\ specified.\ (Note1))$

Parameter	Parameter		Coi	nditions	Min.	Тур.	Max.	Unit
Output Voltage		Vo	T _J = 25°C		23	24	25	V
Line Regulation (Note	e1)	ΔVο	TJ = 25°C	$27 \text{V} \leq \text{V}_{\text{I}} \leq 38 \text{V}$	-	160	300	mV
Ŭ ,	,	ΔνΟ	1J = 25 C	$28V \leq V_I \leq 38V$	-	150	250	mV
Load Degulation (Not	-01)	4)/0	T. 25°C	$1mA \le IO \le 100mA$	-	40	200	mV
Load Regulation (Not	.e i)	ΔVΟ	T _J = 25°C	$1mA \le I_O \le 40mA$	-	20	100	mV
			$27 \text{V} \leq \text{V}_{\text{I}} \leq 38 \text{V}$	$1mA \le IO \le 40mA$	22.8	-	25.2	V
Output Voltage		Vo	27V ≤ V _I ≤ VMAX (Note2)	$1mA \le I_O \le 70mA$	22.8	-	25.2	V
Quiescent Current		lQ	T _J = 25°C		-	2.2	6.0	mA
Quiescent Current	With Line	ΔlQ	$28V \leq V_I \leq 38V$		-	-	1.5	mA
Change	With Load	ΔlQ	1mA ≤ I _O ≤ 40m	A	-	-	0.1	mA
Output Noise Voltage	;	VN	T _A = 25°C, 10H;	z ≤ f ≤ 100kHz	-	200	-	μV/Vo
Temperature Coefficient of VO		ΔV0/ΔΤ	IO = 5mA		-	-2.0	-	mV/°C
Ripple Rejection		RR	$f = 120Hz, 28V \le V_I \le 38V, T_J = 25^{\circ}C$		34	45	-	dB
Dropout Voltage		V_D	T _J = 25°C		-	1.7	-	V

^{1.} The maximum steady state usable output current and input voltage are very dependent on the heat sinking and/or lead length of the package. The data above represent pulse test conditions with junction temperature as indicated at the initiation of tests.

^{2.} Power dissipation $PD \le 0.75W$.

Absolute Maximum Ratings

Parameter	Symbol	Value	Unit
Input Voltage (for $V_O = 5V$ to $8V$) (for $V_O = 12V$ to $18V$) (for $V_O = 24V$)	VI	30 35 40	V V V
Operating Junction Temperature Range	TJ	0 ~ +150	°C
Storage Temperature Range	TSTG	-65 ~ +150	°C

Electrical Characteristics(MC78L05AA) (Continued)

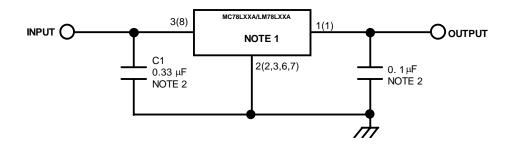
(VI = 10V, IO = 40mA, 0° C \leq TJ \leq 125 $^{\circ}$ C, CI = 0.33 μ F, CO = 0.1 μ F, unless otherwise specified. (Note))

Parameter		Symbol	Соі	nditions	Min.	Тур.	Max.	Unit
Output Voltage		Vo	T _J = 25°C	T _J = 25°C		5.0	5.1	V
Line Regulation (Not	-01)	ΔVο	T.J = 25°C	7V ≤ V _I ≤ 20V	-	8	150	mV
Line Regulation (Not	le i)	ΔνΟ	1J = 25 C	$8V \leq V_I \leq 20V$	-	6	100	mV
Load Regulation (No	sto.1)	4)/0	T 25°C	$1mA \le IO \le 100mA$	-	11	50	mV
Load Regulation (No	ne i)	ΔVΟ	T _J = 25°C	$1mA \le IO \le 40mA$	-	5.0	25	mV
			7V ≤VI ≤20V	$1mA \le IO \le 40mA$	-	-	5.15	V
Output Voltage		Vo	7V ≤V _I ≤ V _{MAX} (Note2)	$1mA \le IO \le 70mA$	4.75	-	5.15	V
Quiescent Current		lQ	T _J = 25°C		-	2.0	5.5	mA
Quiescent Current	With Line	ΔlQ	8V ≤V _I ≤ 20V		-	-	1.5	mA
Change	With Load	ΔlQ	$1\text{mA} \le I_O \le 40 \text{ m}$	nA	-	-	0.1	mA
Output Noise Voltage	е	VN	$T_A = 25^{\circ}C, 10Hz \le f \le 100kHz$		-	40	-	μV/Vo
Temperature Coeffic	cient of VO	$\Delta VO/\Delta T$ IO = 5mA		-	-0.65	-	mV/°C	
Ripple Rejection		RR	f = 120Hz, 8V ≤ V _I ≤ 18V, T _J = 25°C		41	80	-	dB
Dropout Voltage		VD	TJ = 25°C		-	1.7	-	V

^{1.} The maximum steady state usable output current and input voltage are very dependent on the heat sinking and/or lead length of the package. The data above represent pulse test conditions with junction temperature as indicated at the initiation of tests.

^{2.} Power dissipation $PD \le 0.75W$.

Typical Application



'()': 8SOP Type

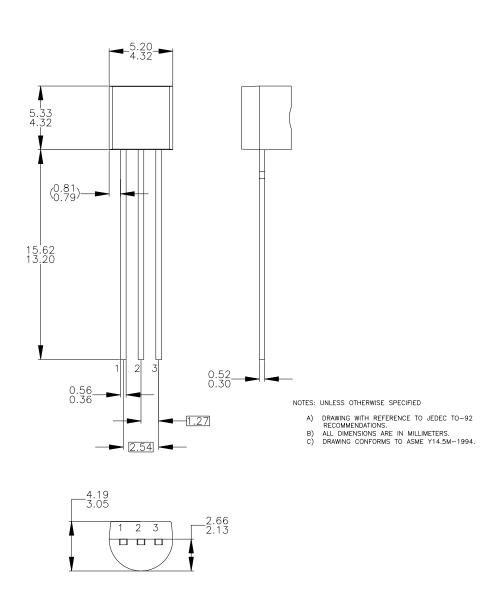
- 1. To specify an output voltage, substitute voltage value for "XX".
- 2. Bypass Capacitors are recommend for optimum stability and transient response and should be located as close as possible to the regulator

Mechanical Dimensions

Package

Dimensions in millimeters

TO-92 Straight Lead for Bulk Packing

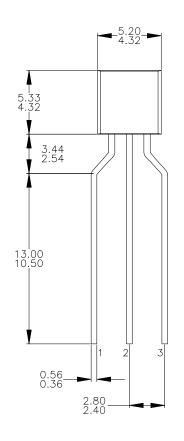


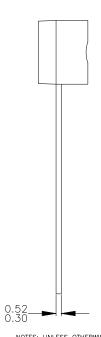
Mechanical Dimensions (Continued)

Package

Dimensions in millimeters

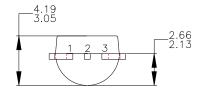
TO-92 Formed Lead For T&R and Ammo Packing





NOTES: UNLESS OTHERWISE SPECIFIED

- A) DRAWING WITH REFERENCE TO JEDEC TO-92 RECOMMENDATIONS.
 B) ALL DIMENSIONS ARE IN MILLIMETERS.
 DRAWING CONFORMS TO ASME Y14.5M-1994.

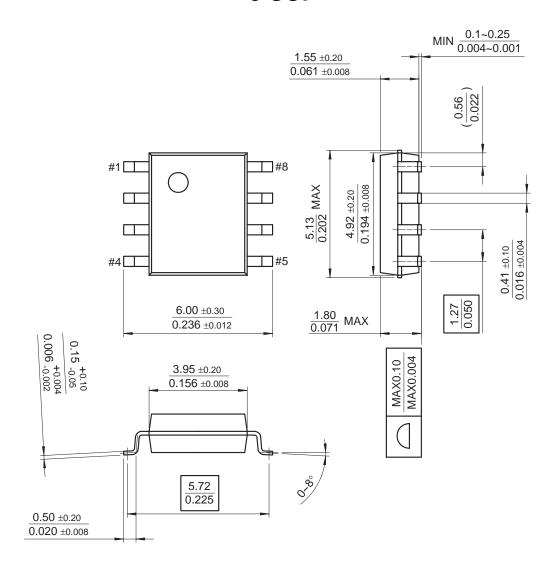


Mechanical Dimensions (Continued)

Package

Dimensions in millimeters

8-SOP

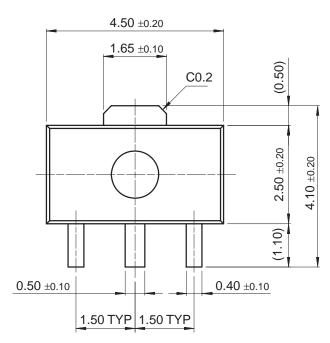


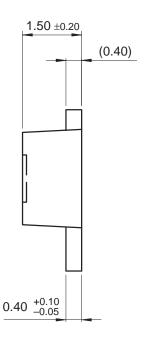
Mechanical Dimensions (Continued)

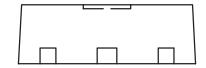
Package

Dimensions in millimeters

SOT-89







Ordering Information

Product Number	Package	Output Voltage Tolerance	Operating Temperature
LM78L05ACZ	TO-92	5%	0 ~ +125°C
LM78L12ACZ	10-92	5%	0 ~ +125 C
Product Number	Package	Output Voltage Tolerance	Operating Temperature
MC78L05ACP			
MC78L06ACP			
MC78L08ACP			
MC78L12ACP	TO-92		
MC78L15ACP			
MC78L18ACP			
MC78L24ACP		5%	0 ~ +125°C
MC78L05ACD]	0 ~ +125°C
MC78L08ACD	8-SOP		
MC78L12ACD			
MC78L05ACH			
MC78L08ACH	SOT-89		
MC78L12ACH			
MC78L05AACP	TO-92	2%	

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- A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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